

### US005648284A

## United States Patent [19]

Kusunoki et al.

Date of Patent:

**Patent Number:** 

[11]

5,648,284

[45]

Jul. 15, 1997

[54] FIELD EFFECT TRANSISTOR INCLUDING SILICON OXIDE FILM AND NITRIDED OXIDE FILM AS GATE INSULATOR FILM AND MANUFACTURING METHOD THEREOF

[75] Inventors: Shigeru Kusunoki; Masahide Inuishi,

both of Hyogo-ken, Japan

Assignee: Mitsubishi Denki Kabushiki Kaisha,

Tokyo, Japan

[21] Appl. No.: 653,090

[22] Filed: May 24, 1996

### Related U.S. Application Data

Continuation of Ser. No. 341,952, Nov. 16, 1994, abandoned, which is a division of Ser. No. 930,932, Aug. 18, 1992, Pat. No. 5,369,297.

[30] Foreign Application Priority Data	[30]	Foreign	Application	<b>Priority</b>	Data
--	------	---------	-------------	-----------------	------

Dec	o. 5, 1991 c. 6, 1991 l. 3, 1992	[JP]	Japan	3-225686 3-323239 4-176873

[56] References Cited U.S. PATENT DOCUMENTS

9/1988 Haddad et al. ...... 437/24 4,774,197

OTHER PUBLICATIONS

Kusunoki, "Hot-Carrier-resistant Structure By Re-Oxidized Nitrided Oxide Sidewall For Hoghly Reliable and High Performance LDD MOSFETS", IEDM, IEEE, pp. 649-652. 1991.

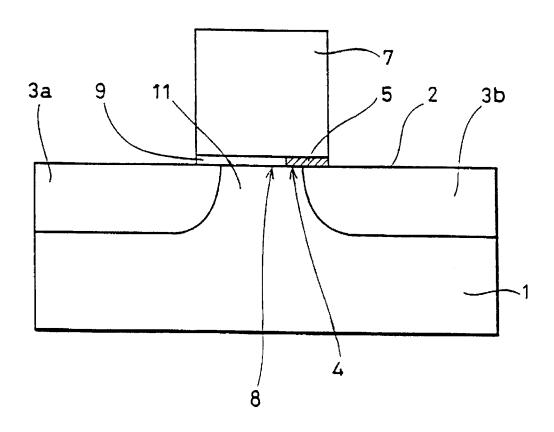
Primary Examiner-Charles L. Bowers, Jr. Assistant Examiner-Lynne A. Gurley

Attorney, Agent, or Firm-Lowe, Price, LeBlanc & Becker

ABSTRACT

An N type field effect transistor having a higher resistivity to hot carriers and exhibiting a higher current handling capability even when used at a low gate voltage, and a method of manufacturing such a transistor are provided. A nitrided oxide film is formed on a drain avalanche hot carrier injection region. The nitrided oxide film is highly resistive to drain avalanche hot carriers as compared to a silicon oxide film. The silicon oxide film is formed on a channel hot electron injection region. The silicon oxide film is highly resistive to channel hot electrons as compared to the nitrided oxide film. A major portion of a gate insulator film is a silicon oxide film. The silicon oxide film exhibits a higher current handling capability at a low gate voltage as compared to the nitrided oxide film.

#### 7 Claims, 39 Drawing Sheets



437/42, 241



FIG.1

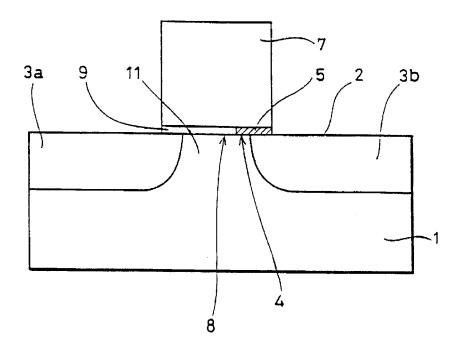


FIG. 2

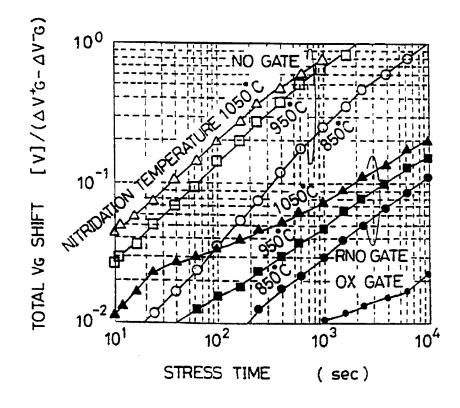




FIG. 3 PRIOR ART

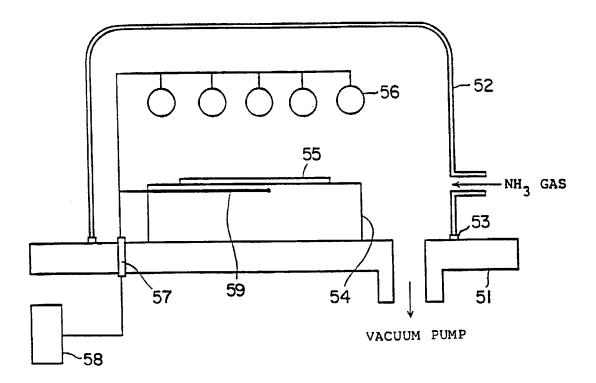
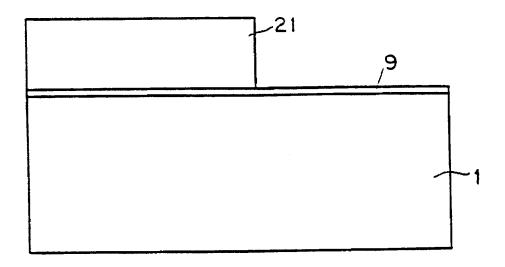


FIG. 4



Jul. 15, 1997

FIG. 5

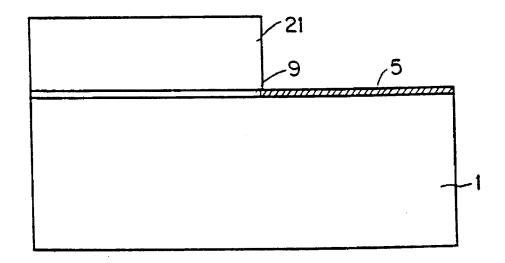
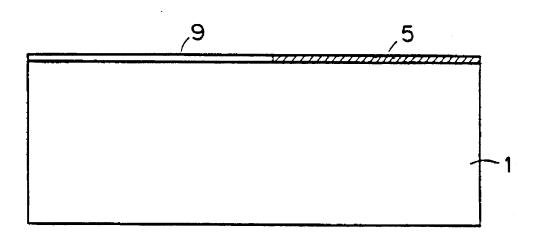


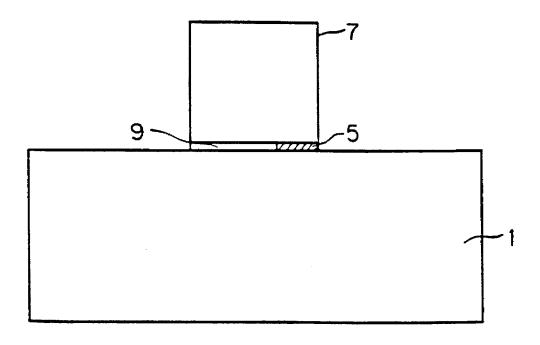


FIG. 6



Jul. 15, 1997

FIG. 7



# DOCKET A L A R M

# Explore Litigation Insights



Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

## **Real-Time Litigation Alerts**



Keep your litigation team up-to-date with **real-time** alerts and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

## **Advanced Docket Research**



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

## **Analytics At Your Fingertips**



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

## API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

#### **LAW FIRMS**

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

#### **FINANCIAL INSTITUTIONS**

Litigation and bankruptcy checks for companies and debtors.

## **E-DISCOVERY AND LEGAL VENDORS**

Sync your system to PACER to automate legal marketing.

